NSN 5961-01-372-2063

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View Online at https://aerobasegroup.com/nsn/5961-01-372-2063 **Inclosure Material:** Metal **Overall Length:** Between 0.790 inches and 0.810 inches **Overall Height:** Between 0.149 inches and 0.187 inches Overall Width: Between 0.245 inches and 0.255 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 3.5 breakdown voltage, emitter-to-base, collector open and 45.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 0.50 milliamperes base current, dc preset **Power Rating Per Characteristic:** 6.0 watts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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